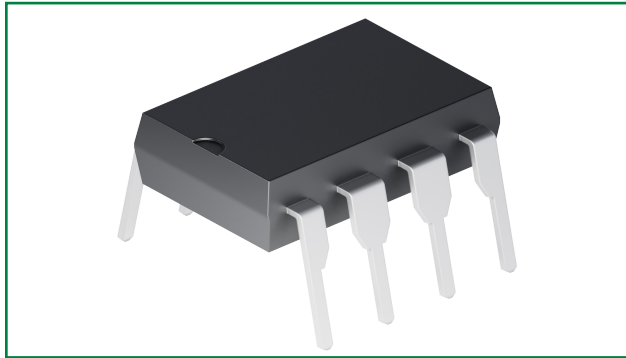


LBA110

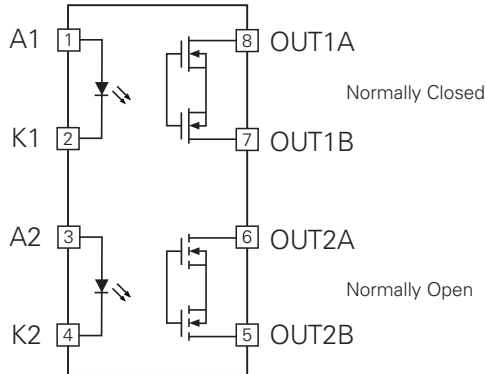
350V, 120 mA Dual Single-Pole Relays:
1-Form-A (NO) and 1-Form-B (NC)

Key Attributes

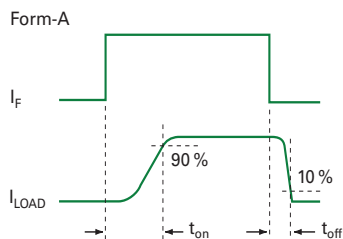
Characteristic	Rating	Unit
Blocking Voltage	350	V _P
Load Current	120	mA _{RMS} /mA _{DC}
On-resistance (max.)	35	Ω
LED Current to Operate	2	mA



Pin Configuration



Switching Characteristics of Normally Open Device



Description



LBA110 comprises two independent 350 V, 120 mA, 35 Ω solid state relays: one single-pole, normally open (1-Form-A) relay and one single-pole, normally closed (1-Form-B) relay.

LBA110 is designed to provide an ideal solution where a complementary Form-A/Form-B relay pair is required.

Features

- 3750V_{RMS} Input/Output Isolation
- 100 % Solid State
- Low Drive Power Requirements
- No EMI/RFI Generation
- FCC Compatible
- VDE Compatible

Applications

- Telecommunications
- Instrumentation
- Multiplexers
- Data Acquisition
- Electronic Switching
- I/O Subsystems
- Utility Meters (gas, oil, electric and water)
- Medical Equipment—Patient/Equipment Isolation
- Security
- Industrial Controls

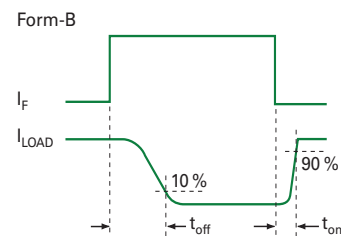
Approvals

- UL 1577 Recognized Component: File E76270
- CSA Certified Component: Certificate # 1175739
- TUV EN 62368-1: Certificate # B 082667 0008

Ordering Information

Part Number	Description
LBA110	8-Pin DIP (50/Tube)
LBA110S	8-Pin Surface Mount (50/Tube)
LBA110STR	8-Pin Surface Mount (1000/Reel)
LBA110P	8-Pin Flat Pack (50/Tube)
LBA110PTR	8-Pin Flat Pack (1000/Reel)

Switching Characteristics of Normally Closed Device



Specifications

Absolute Maximum Ratings

Parameter	Ratings	Units
Blocking Voltage	350	V _P
Reverse Input Voltage	5	V
Input Control Current	50	mA
Peak (10 ms)	1	A
Input Power Dissipation ¹	150	mW
Total Power Dissipation ²	800	
Isolation Voltage, Input to Output	3750	V _{RMS}
Operational Temperature, Ambient	–40 to +85	°C
Storage Temperature	–40 to +125	

¹ Derate linearly 1.33 mW/°C

² Derate output power linearly 6.67 mW/°C

Absolute Maximum Ratings are stress ratings. Stresses in excess of these ratings can cause permanent damage to the device. Functional operation of the device at conditions beyond those indicated in the operational sections of this data sheet is not implied.

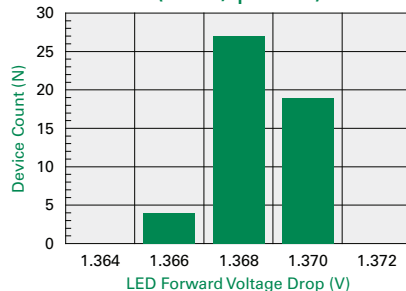
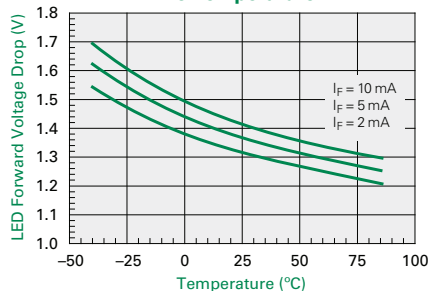
Typical values are characteristic of the device at +25 °C, and are the result of engineering evaluations. They are provided for information purposes only, and are not part of the manufacturing testing requirements.

Electrical Characteristics @ 25 °C

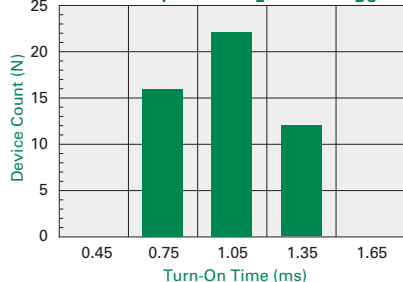
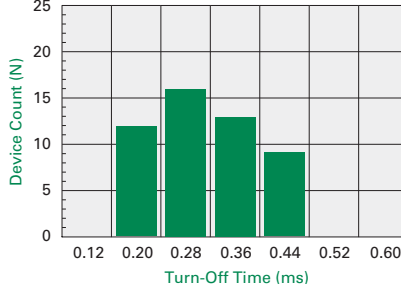
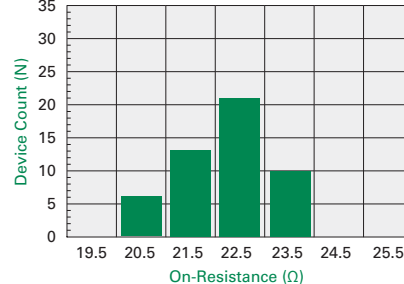
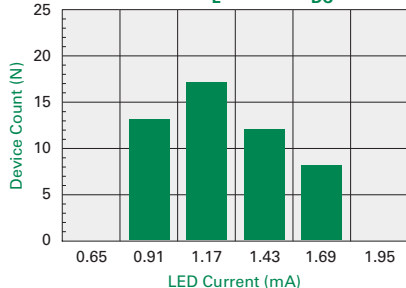
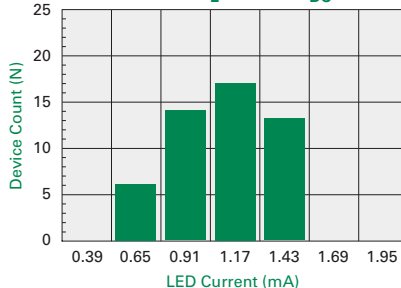
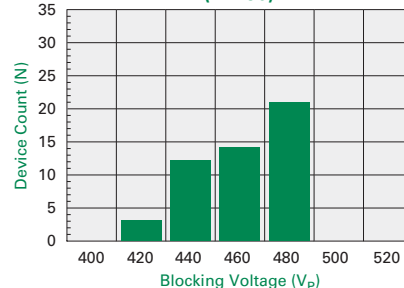
Parameter	Conditions	Symbol	Value			Units
			Minimum	Typical	Maximum	
Output Characteristics						
Blocking voltage	I _L = 1 μA	V _{DRM}	350	—	—	V _P
Load current:						
Continuous ¹	—	I _L	—	—	120	mA _{RMS} /mA _{DC}
Peak	t = 10 ms	I _{LPK}	—	—	±350	mA _P
On-resistance	I _L = 120 mA	R _{ON}	—	25	35	Ω
Off-state leakage current	V _L = 350 V _P	I _{LEAK}	—	—	1	μA
Switching speeds:						
Turn-on	I _F = 5 mA, V _L = 10 V	t _{on}	—	—	3	ms
Turn-off		t _{off}	—	—	3	
Output Capacitance	V = 50V, f = 1 MHz	C _{OUT}	—	25	—	pF
Input Characteristics						
Input control current to activate	I _L = 120 mA	I _F	—	—	2	mA
Input voltage drop to deactivate	—	V _F	0.8	—	—	V
Input voltage drop	—	V _F	0.9	1.36	1.5	
Reverse input current	V _R = 5V	I _R	—	—	10	μA
Common Characteristics						
Capacitance, input to output	V _{IO} = 0V, f = 1 MHz	C _{IO}	—	3	—	pF

¹ NOTE: If both poles operate simultaneously, then load current must be derated so as not to exceed the package power dissipation value.

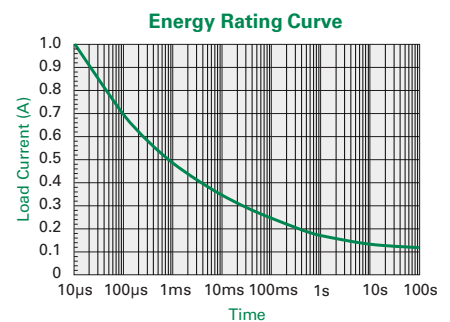
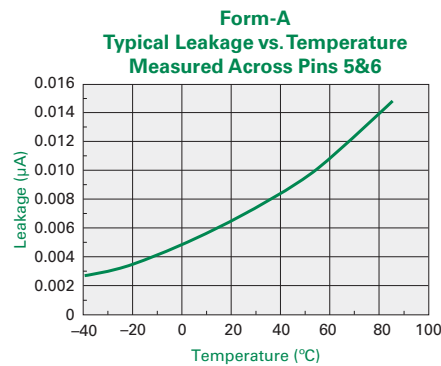
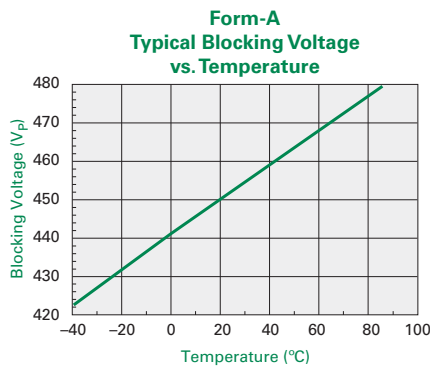
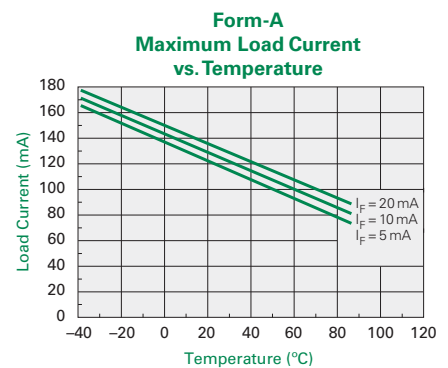
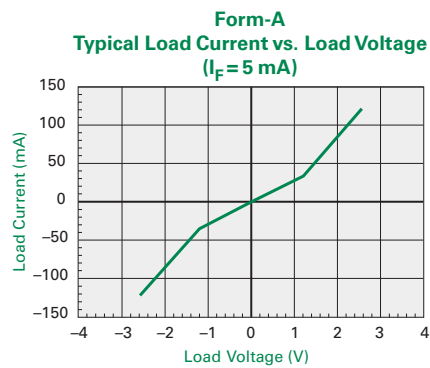
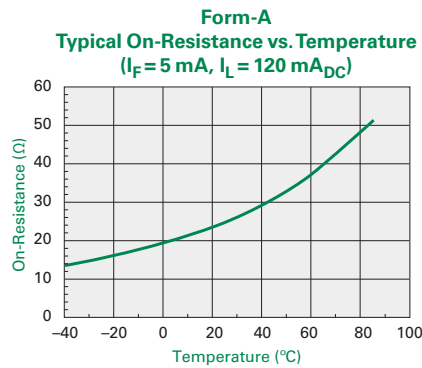
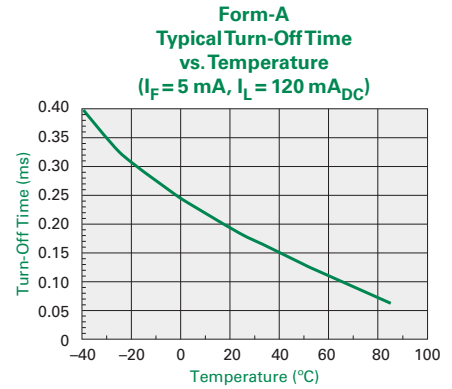
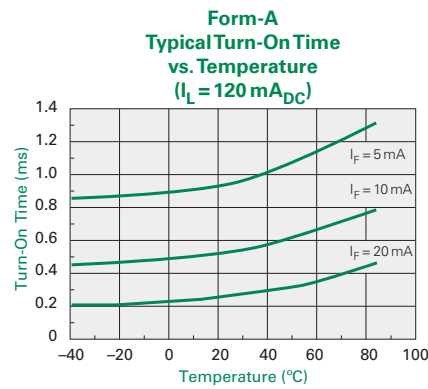
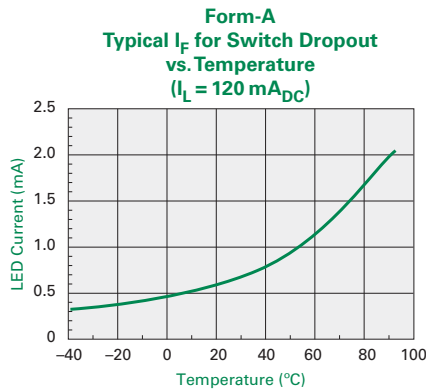
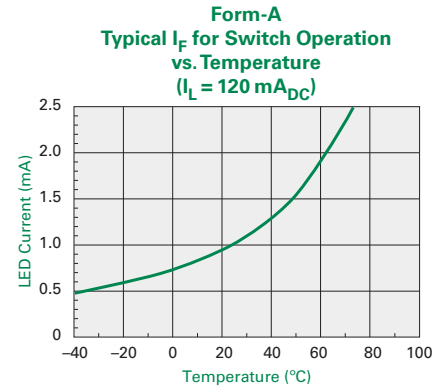
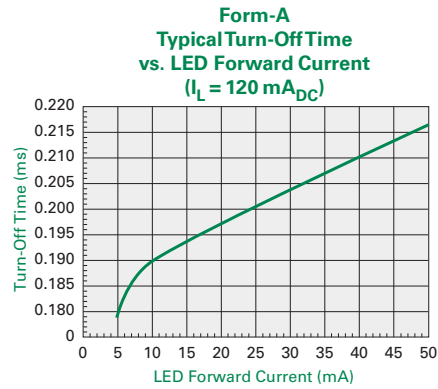
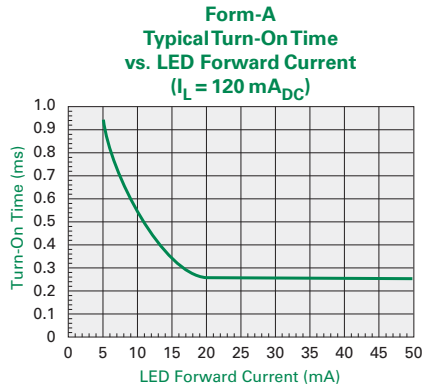
Form-A/Form-B PERFORMANCE DATA*

Typical LED Forward Voltage Drop
(N = 50, $I_F = 5\text{ mA}$)Typical LED Forward Voltage Drop
vs. Temperature

Form-A PERFORMANCE DATA*

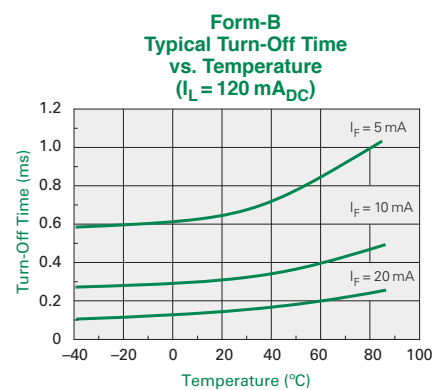
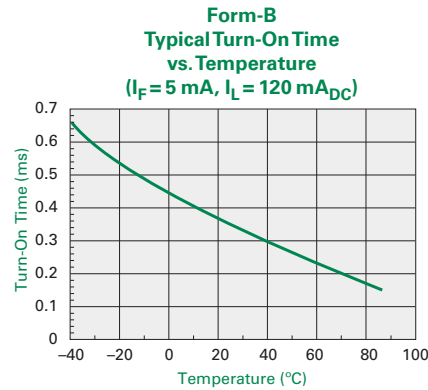
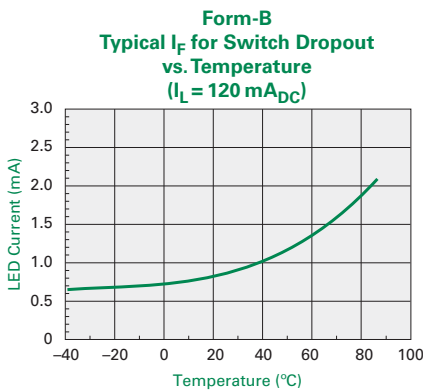
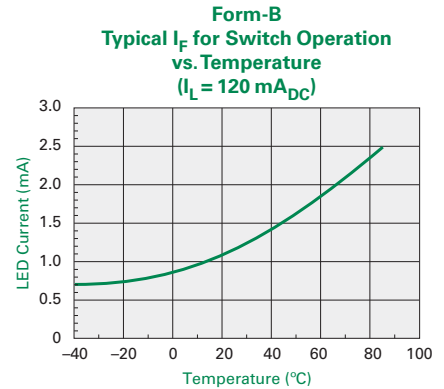
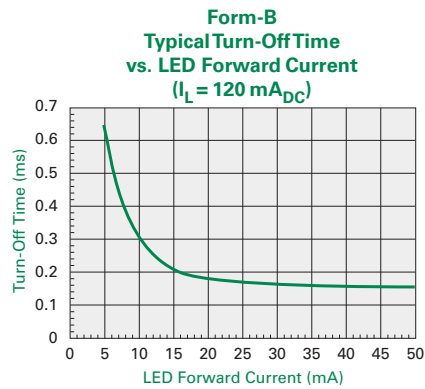
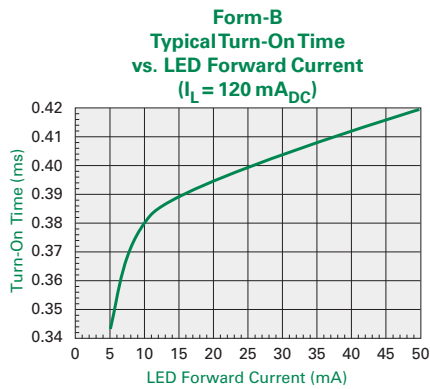
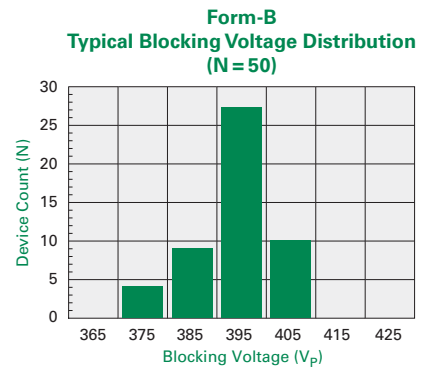
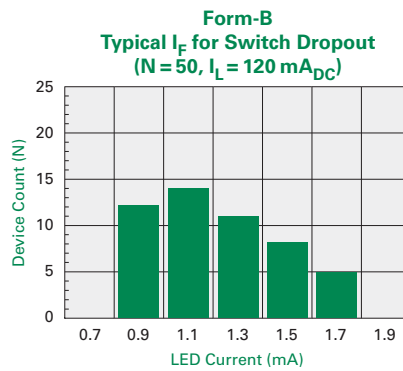
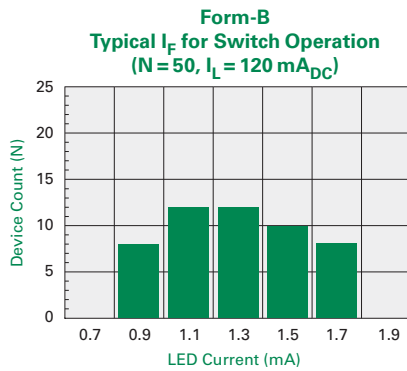
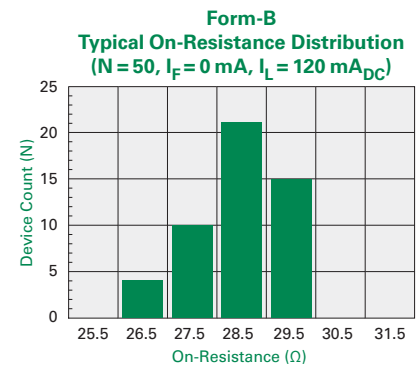
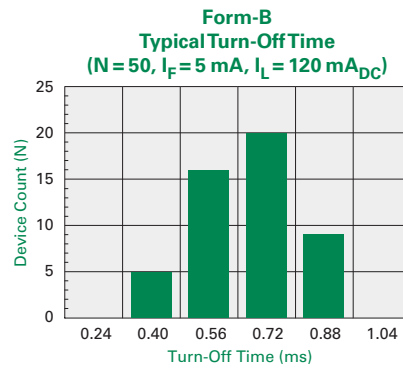
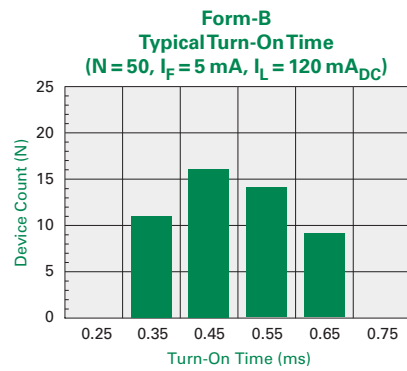
Form-A
Typical Turn-On Time
(N = 50, $I_F = 5\text{ mA}$, $I_L = 120\text{ mA}_{DC}$)Form-A
Typical Turn-Off Time
(N = 50, $I_F = 5\text{ mA}$, $I_L = 120\text{ mA}_{DC}$)Form-A
Typical On-Resistance Distribution
(N = 50, $I_F = 5\text{ mA}$, $I_L = 120\text{ mA}_{DC}$)Form-A
Typical I_F for Switch Operation
(N = 50, $I_L = 120\text{ mA}_{DC}$)Form-A
Typical I_F for Switch Dropout
(N = 50, $I_L = 120\text{ mA}_{DC}$)Form-A
Typical Blocking Voltage Distribution
(N = 50)*Unless otherwise noted, data presented in these graphs is typical of device operation at $T_A = 25^\circ\text{C}$.

Form-A PERFORMANCE DATA*



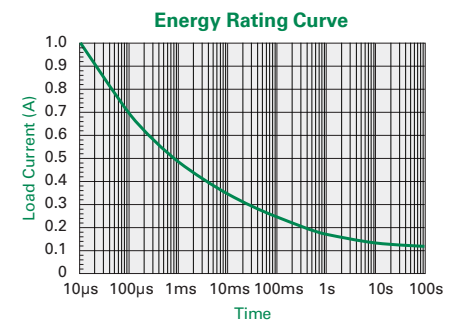
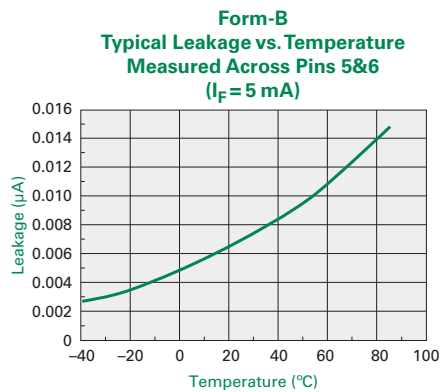
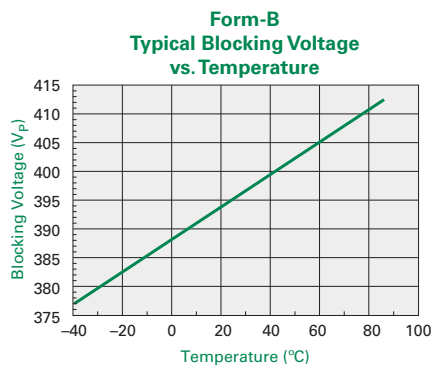
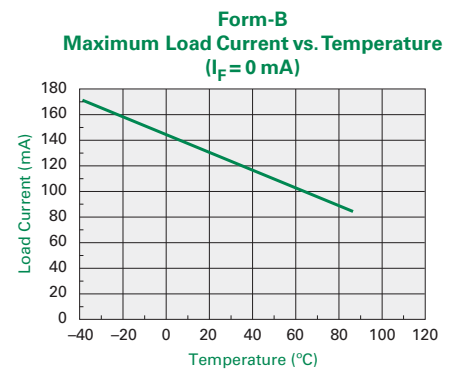
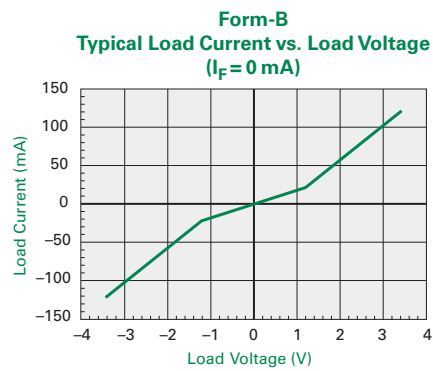
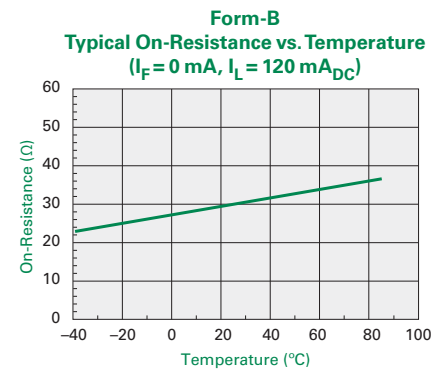
*Unless otherwise noted, data presented in these graphs is typical of device operation at $T_A = 25^\circ\text{C}$.

Form-B PERFORMANCE DATA*



*Unless otherwise noted, data presented in these graphs is typical of device operation at $T_A = 25^\circ\text{C}$.

Form-B PERFORMANCE DATA*



*Unless otherwise noted, data presented in these graphs is typical of device operation at $T_A = 25^\circ\text{C}$.

Manufacturing Information

Moisture Sensitivity



All plastic encapsulated semiconductor packages are susceptible to moisture ingress. Littelfuse classifies its plastic encapsulated devices for moisture sensitivity according to the latest version of the joint industry standard, **IPC/JEDEC J-STD-020**, in force at the time of product evaluation. We test all of our products to the maximum conditions set forth in the standard, and guarantee proper operation of our devices when handled according to the limitations and information in that standard as well as to any limitations set forth in the information or standards referenced below.

Failure to adhere to the warnings or limitations as established by the listed specifications could result in reduced product performance, reduction of operable life, and/or reduction of overall reliability.

This product carries a **Moisture Sensitivity Level (MSL)** classification as shown below, and should be handled according to the requirements of the latest version of the joint industry standard **IPC/JEDEC J-STD-033**.

Device	Moisture Sensitivity Level (MSL) Classification
LBA110S / LBA110P	MSL 1

ESD Sensitivity



This product is ESD Sensitive, and should be handled according to the industry standard **JESD-625**.

Soldering Profile

Provided in the table below is the **IPC/JEDEC J-STD-020** Classification Temperature (T_C) and the maximum dwell time ($T_C - 5^\circ\text{C}$). The Classification Temperature sets the Maximum Body Temperature allowed for these devices during reflow soldering processes.

Device	Classification Temperature (T_C)	Dwell Time (T_P)	Max Reflow Cycles
LBA110S	250°C	30 seconds	3
LBA110P	260°C	30 seconds	3

For through-hole devices, the maximum pin temperature and maximum dwell time through all solder waves is provided in the table below. Dwell time is the interval beginning when the pins are initially immersed into the solder wave until they exit the solder wave. For multiple waves, the dwell time is from entering the first wave until exiting the last wave. During this time, pin temperatures must not exceed the maximum temperature given in the table below. Body temperature of the device must not exceed the limit shown in the table below at any time during the soldering process.

Device	Maximum Pin Temperature	Maximum Body Temperature	Maximum Dwell Time	Wave Cycles
LBA110	260°C	250°C	10 seconds*	1

*Total cumulative duration of all waves.

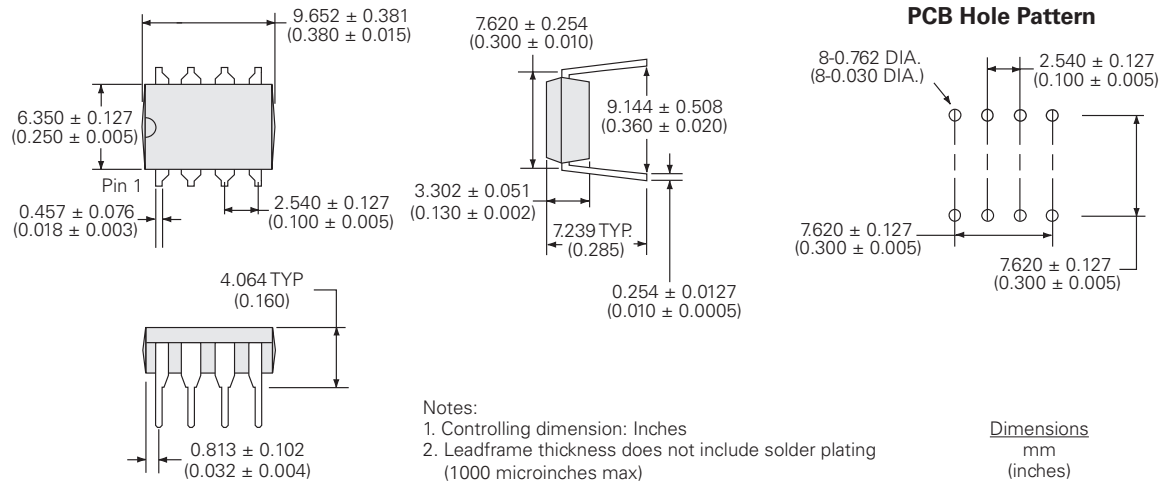
Board Wash

Littelfuse recommends the use of no-clean flux formulations. Board washing to reduce, or remove flux residue following the solder reflow process is acceptable, provided proper precautions are taken to prevent damage to the device. These precautions include, but are not limited to: Using a low pressure wash and providing a follow-up bake cycle sufficient to remove any moisture trapped within the device, due to the washing process. Due to the variability of the wash parameters used to clean the board, determination of the bake temperature and duration necessary to remove the moisture trapped within the package is the responsibility of the user (assembler). Cleaning, or drying methods that employ ultrasonic energy may damage the device and should not be used. Additionally, the device must not be exposed to halide flux or solvents.

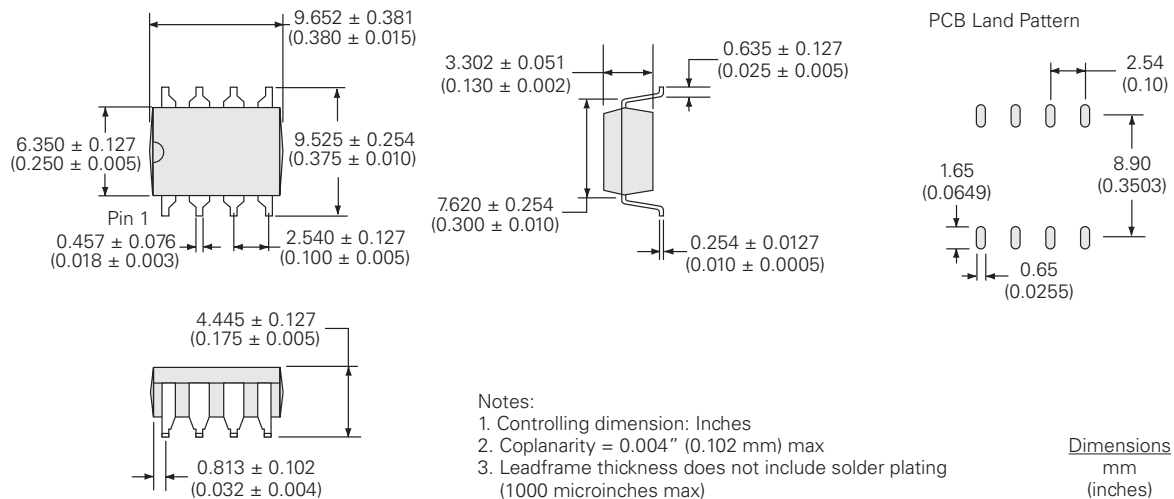


Mechanical Dimensions

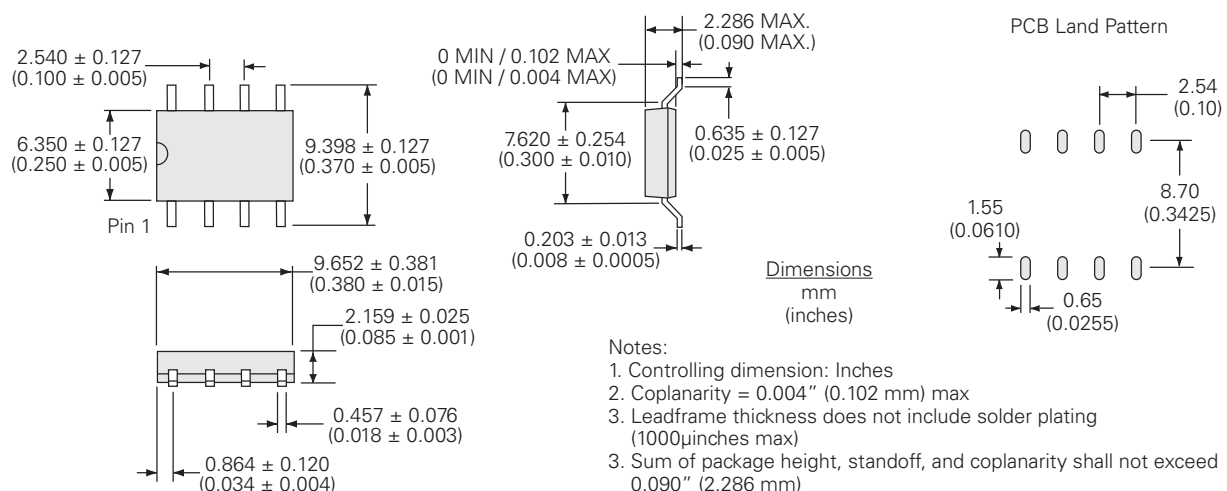
LBA110



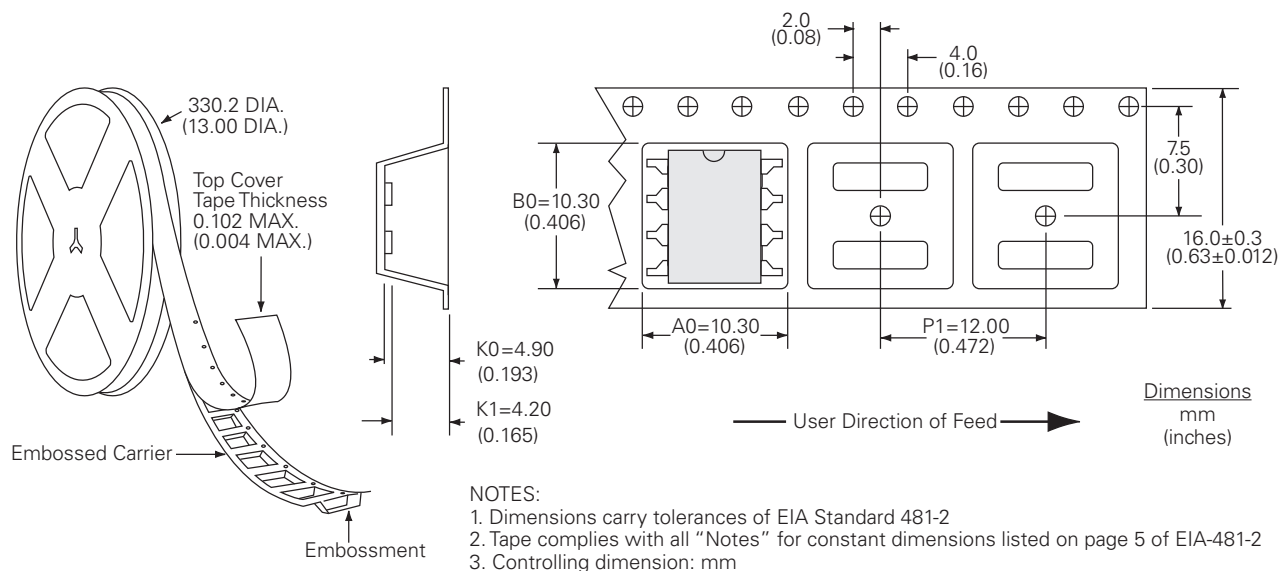
LBA110S



LBA110P



LBA110STR Tape and Reel



LBA110PTR Tape and Reel

